TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2953

Chopper Regulator, DC-DC Converter and Motor Drive Applications

Low drain-source ON resistance : R_{DS} (ON) = 0.31 Ω (typ.)

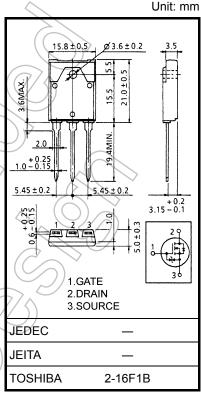
• High forward transfer admittance : $|Y_{fs}| = 15 \text{ S (typ.)}$

• Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 600 V)

• Enhancement mode : V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	600	$\langle \langle \psi \rangle \rangle$	
Drain-gate voltage (Ro	_{SS} = 20 kΩ)	V_{DGR}	600	V	
Gate-source voltage		V_{GSS}	±30	V	
Drain current	DC (Note 1)	I _D	15	A	
	Pulse (Note 1)	I _{DP}	60	^	
Drain power dissipation	n (Tc = 25°C)	PD	90	W	
Single pulse avalanche	e energy (Note 2)	E _{AS}	1026	mJ	
Avalanche current		I _{AR})) 15	Α	
Repetitive avalanche e	nergy (Note 3)	EAR	9	mJ	
Channel temperature		T _{ch}	150	Ĵ¢	
Storage temperature ra	ange	Tstg	-55 to 150	~e	



Weight: 5.8 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th} (ch-c)	1.39	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	41.6	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 7.98 mH, R_G = 25 Ω , I_{AR} = 15 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

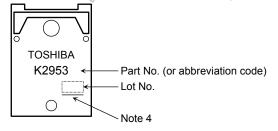
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V _{GS} = ±25 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 600 V, V _{GS} = 0 V	7	_	100	μA
Drain-source br	eakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	600	/	_	V
Gate threshold v	oltage/	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) /_	4.0	V
Drain-source O	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 8.0 A) 	0.31	0.4	Ω
Forward transfer	r admittance	Y _{fs}	V _{DS} = 10 V, I _D = 8.0 A	8.0	15.0	_	S
Input capacitano	e	C _{iss}		_	3520	_	
Reverse transfe	r capacitance	C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	20	_	pF
Output capacita	nce	Coss		_	300		
Switching time	Rise time	t _r	$V_{GS} \stackrel{10V}{\underset{OV}{\prod}} \stackrel{I_{D}=8.0A}{\underset{OV}{\bigcap}} V_{OUT}$	- (50	\(\frac{1}{2}\)	
	Turn-on time	t _{on}			100) _	
	Fall time	t _f	v _{DD} =300V	(A)	60	_	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm w} = 10 \mu \rm s$) –	325	_	
Total gate charg plus gate-drain)		Qg			80	_	
Gate-source ch	arge	Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 15 \text{ A}$	_	48	_	nC
Gate-drain ("mil	ler") Charge	Qgd		_	32		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	15	Α
Pulse drain reverse current (Note 1)	I _{DRP}	-	_	_	60	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 15 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 15 A, V _{GS} = 0 V	_	620	_	ns
Reverse recovery charge	Qrr	dl _{DR} / dt = 100 A / μs	_	7.5	_	μC

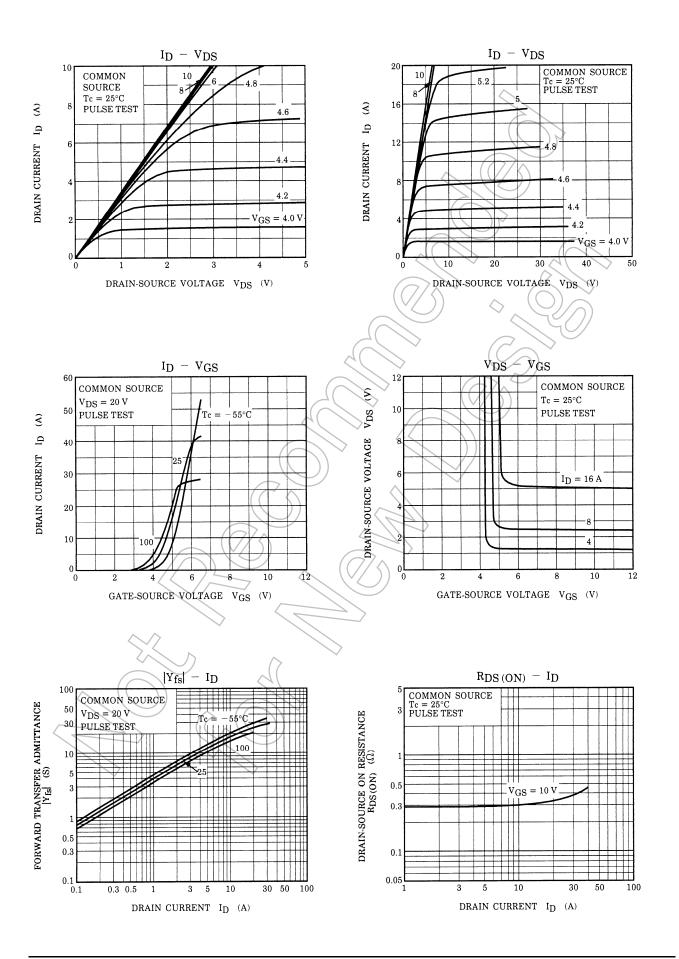
Marking

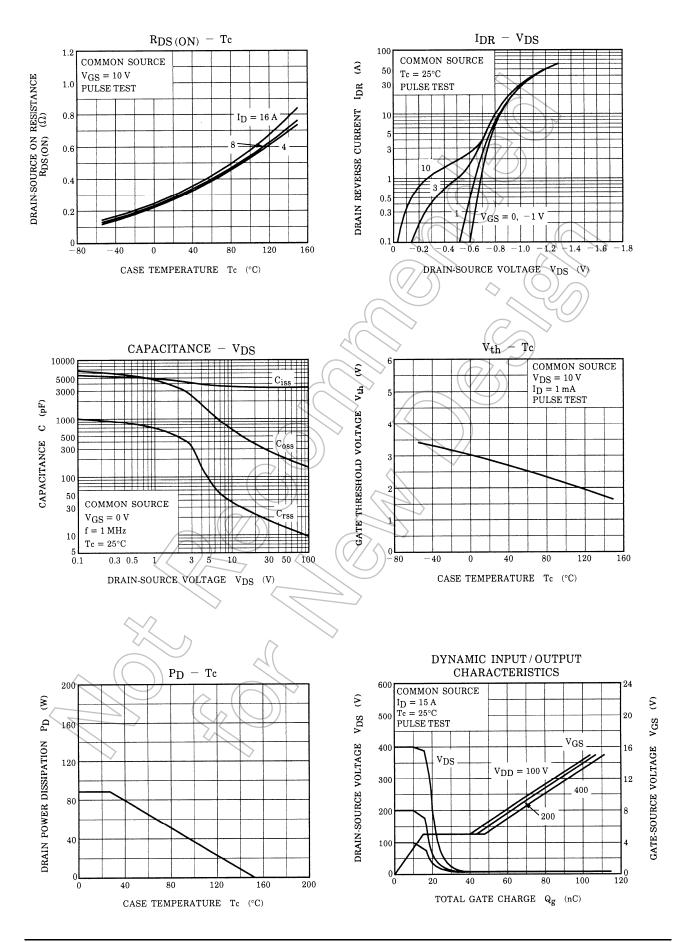


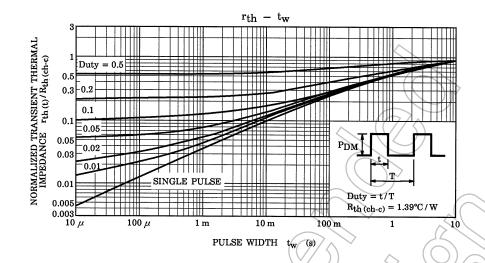
Note 4: A line under a Lot No. identifies the indication of product Labels.

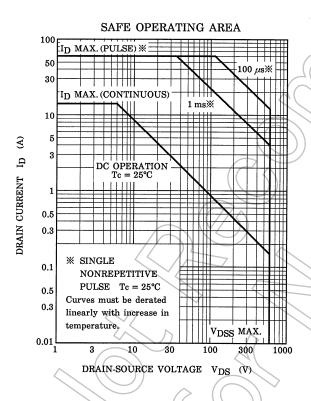
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

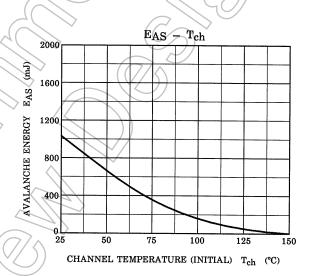
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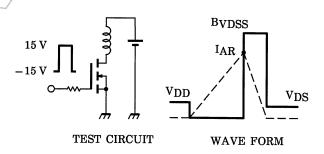












$$R_G$$
 = 25 Ω
 V_{DD} = 90 V, L = 7.98 mH

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^{2} \cdot \left(\frac{BVDSS}{BVDSS - VDD} \right)$$

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